



#### 60V NPN MEDIUM POWER LOW SATURATION TRANSISTOR IN SOT223

#### **Description**

This bipolar junction transistor (BJT) is designed to meet the stringent requirements of automotive applications.

#### **Mechanical Data**

- Case: SOT223
- Case Material: Molded Plastic. "Green" Molding Compound;
  UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—Matte Tin Plated Leads;
  Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.112 grams (Approximate)

#### **Features**

- BV<sub>CEO</sub> > 60V
- I<sub>C</sub> = 6A High Continuous Collector Current
- I<sub>CM</sub> = 20A Peak Pulse Current
- Low Saturation Voltage V<sub>CE(sat)</sub> < 60mV @ 1A</li>
- R<sub>SAT</sub> = 35mΩ for a Low Equivalent On-Resistance
- hFE Specified up to 10A for High Gain Hold-Up
- Complementary PNP Type: ZX5T951GQ
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen- and Antimony-Free. "Green" Device (Note 3)
- The ZX5T851GQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.

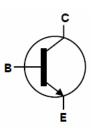
https://www.diodes.com/quality/product-definitions/

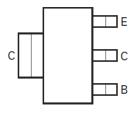
### **Applications**

- Emergency Lighting Circuits
- MOSFET & IGBT Gate Drivers
- · Solenoid, Relay and Actuator Drivers
- DC Modules
- Motor Control



Top View





Device Symbol

Top View Pin-Out

#### Ordering Information (Note 4)

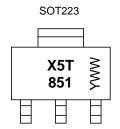
Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
ZX5T851GQTC	Automotive	X5T851	13	12	4000

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.



## **Marking Information**



X5T 851 = Product Type Marking Code YWW = Date Code Marking Y or  $\overline{Y}$  = Last Digit of Year (ex: 0= 2020) WW or  $\overline{W}W$  = Week Code (01~53)

## Absolute Maximum Ratings (@ TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	150	V
Collector-Emitter Voltage	V <sub>CEO</sub>	60	V
Emitter-Base Voltage	V <sub>EBO</sub>	7	V
Continuous Collector Current	Ic	6	Α
Peak Pulse Current	I <sub>CM</sub>	20	Α

## Thermal Characteristics (@ TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
	(Note 5)		3.0	
Power Dissipation	(Note 6)	D-	2.0	W
Power Dissipation	(Note 7)	P <sub>D</sub>	1.6	VV
	(Note 8)		1.2	
	(Note 5)		41.7	
Thermal Resistance, Junction to Ambient	(Note 6)		62.5	
Thermal Resistance, Junction to Ambient	(Note 7)	$R_{\theta JA}$	78.1	°C/W
	(Note 8)		104	
Thermal Resistance Junction to Lead	(Note 9)	$R_{ heta JL}$	10.5	
Operating and Storage Temperature Range	T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C	

## ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

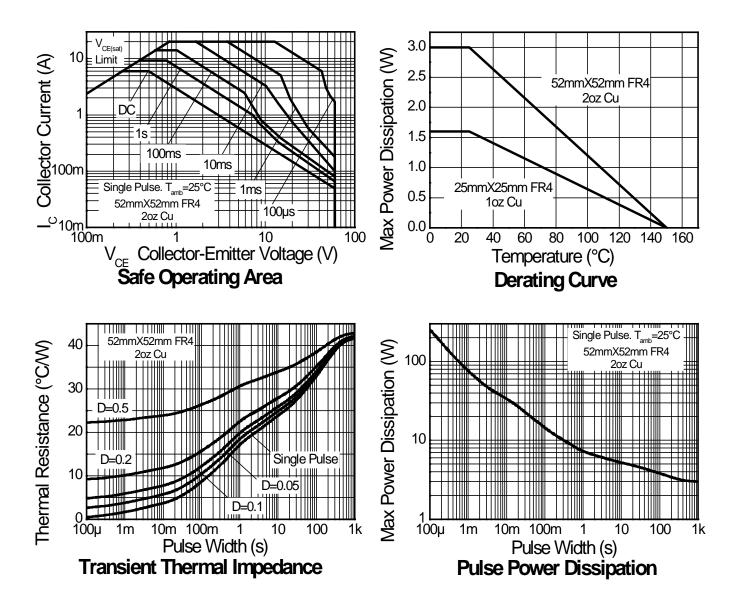
Notes: 5. For a device mounted with the collector lead on 50mm x 50mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

- 6. Same as Note 5 except the device is mounted on 25mm x 25mm 2oz copper.
- 7. Same as Note 5 except the device is mounted on 25mm x 25mm 1oz copper.
- 8. Same as Note 5 except the device is mounted on minimum recommended pad layout.
- 9. Thermal resistance from junction to solder-point (at the end of the collector lead).
- 10. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

ZX5T851GQ Document Number DS42537 Rev. 1 - 2



# **Thermal Characteristics and Derating Information**





# Electrical Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

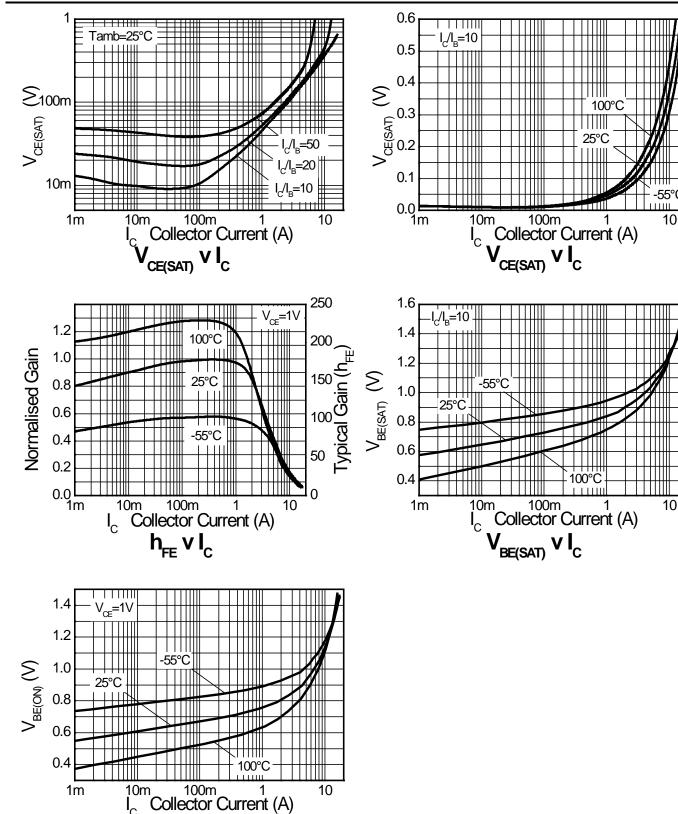
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	150	190	_	V	$I_{C} = 100 \mu A$
Collector-Emitter Breakdown Voltage	BV <sub>CER</sub>	150	190	_	V	$I_C = 1\mu A, R_B \le 1k\Omega$
Collector-Emitter Breakdown Voltage (Note 11)	BV <sub>CEO</sub>	60	80	_	V	I <sub>C</sub> = 10mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	7	8.1	_	V	I <sub>E</sub> = 100μA
Collector Cut-Off Current	I <sub>CBO</sub>	_	<1	20 0.5	nA	V <sub>CB</sub> = 120V
					μA	V <sub>CB</sub> = 120V, T <sub>A</sub> = +100°C
Collector Cut-Off Current	l <sub>CER</sub> R <sub>B</sub> ≤ 1kΩ	_	<1 —	20 0.5	nΑ μΑ	V <sub>CB</sub> = 120V V <sub>CB</sub> = 120V, T <sub>A</sub> = +100°C
Emitter Cut-Off Current	I <sub>EBO</sub>	_	<1	10	nA	V <sub>EB</sub> = 6V
	V <sub>CE(sat)</sub>	_	20	30	mV	$I_C = 100 \text{mA}, I_B = 5 \text{mA}$
		_	45	60		I <sub>C</sub> = 1A, I <sub>B</sub> = 100mA
Collector-Emitter Saturation Voltage (Note 11)		_	50	70		I <sub>C</sub> = 1A, I <sub>B</sub> = 50mA
		_	100	135		I <sub>C</sub> = 2A, I <sub>B</sub> = 50mA
		_	210	260		I <sub>C</sub> = 6A, I <sub>B</sub> = 300mA
Base-Emitter Saturation Voltage (Note 11)	V <sub>BE(sat)</sub>	_	1000	1100	mV	I <sub>C</sub> = 6A, I <sub>B</sub> = 300mA
Base-Emitter Turn-On Voltage (Note 11)	V <sub>BE(on)</sub>	_	940	1050	mV	I <sub>C</sub> = 6A, V <sub>CE</sub> = 1V
		100	200	_		$I_C = 10mA, V_{CE} = 1V$
DC Current Gain (Note 11)	h <sub>FE</sub>	100	200	300		$I_C = 2A, V_{CE} = 1V$
De Current Gain (Note 11)		55	105		_	$I_C = 5A, V_{CE} = 1V$
		20	40			$I_C = 10A, V_{CE} = 1V$
Output Capacitance	$C_{obo}$	_	31	-	pF	V <sub>CB</sub> = 10V. f = 1MHz
Current Gain-Bandwidth Product	f⊤		130	_	MHz	$V_{CE} = 5V, I_{C} = 100mA,$ f = 100MHz
Switching Times	t <sub>on</sub>	_	42	_	no	$I_C = 1A, V_{CC} = 10V,$
Switching Times	t <sub>off</sub>	_	760	_	ns	$I_{B1} = -I_{B2} = 100 \text{mA}$

Note:

11. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%.



## Typical Electrical Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)



1m

10m

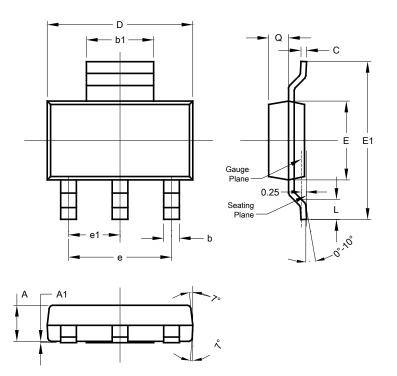
<sub>BE(ON)</sub> v l<sub>C</sub>

10



## **Package Outline Dimensions**

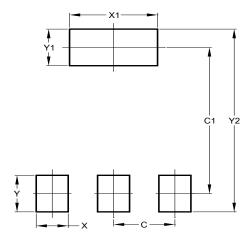
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b	0.60	0.80	0.70		
b1	2.90	3.10	3.00		
C	0.20	0.30	0.25		
D	6.45	6.55	6.50		
Е	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е	-	-	4.60		
e1	-	-	2.30		
L	0.85	1.05	0.95		
Ø	0.84	0.94	0.89		
All Dimensions in mm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	2.30
C1	6.40
X	1.20
X1	3.30
Υ	1.60
Y1	1.60
Y2	8.00



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